DIGITRON SEMICONDUCTORS

MAC219 SERIES — SILICON BIDIRECTIONAL THYRISTORS

Available Non-RoHS (standard) or RoHS compliant (add PBF suffix).
Available as "HR" (high reliability) screened per MIL-PRF-19500, JANTX level. Add "HR" suffix to base part number.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak repetitive off-state voltage(1) (T_J = -40 to +125°C) MAC219-4 MAC219-6 MAC219-8 MAC219-10	V_{DRM}	 200 400 600 800	Volts
Peak gate voltage	V_{GM}	±10	Volts
RMS on-state current (conduction angle = 360°, T_C = 80°C)	$I_{T(RMS)}$	8.0	Amps
Peak non-repetitive surge current (1 cycle, 60 Hz)	I_{TSM}	100	Amps
Circuit fusing considerations (t = 8.3ms)	I^2t	35	A^2s
Peak gate power (T_C = 80°C, pulse width = 2μs)	P_{GM}	16	Watts
Average gate power (T_C = 80°C, t = 8.3ms)	$P_{G(AV)}$	0.35	Watts
Peak gate trigger current (Pulse width = 1.0μs)	I_{GM}	4.0	Amps
Operating junction temperature range	T_J	-40 to +125	°C
Storage temperature range	T_{stg}	-40 to +150	°C

Note 1: Ratings apply for open gate conditions. Thyristor devices shall not be tested with a constant current source for blocking capability such that the voltage applied exceeds the rated blocking voltage.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Maximum	Unit
Thermal resistance, junction to case	$R_{\Theta JC}$	2.2	°C/W

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Typ.	Max	Unit
Peak blocking current (either direction) (V_D = Rated V_{DRM} @ T_J = 25°C) (V_D = Rated V_{DRM} @ T_J = 125°C)	I_{DRM}	 - -	 - -	 10 2	 μA mA
Peak on-state voltage (either direction) (I_{TM} = 11.3A peak, pulse width = 1 to 2 ms, duty cycle ≤ 2%)	V_{TM}	-	1.7	2.0	Volts
Gate trigger current (continuous dc) (main terminal voltage = 12V, R_L = 12Ω) Trigger mode MT2(+),G(+); MT2(+),G(-); MT2(-),G(-)	I_{GT}	 -	 -	 100	mA
Gate trigger voltage (continuous dc) (main terminal voltage = 12V, R_L = 100Ω) MT2(+),G(+) MT2(+),G(-) MT2(-),G(-) (main terminal voltage= Rated V_{DRM}, R_L = 10kΩ, T_J = 125°C) MT2(+), G(+); MT2(-), G(-); MT2(+), G(-)	V_{GT}	 - - - 0.2	 0.9 0.9 1.1 -	 2 2 2 -	Volts

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D I G I T R O N S E M I C O N D U C T O R S

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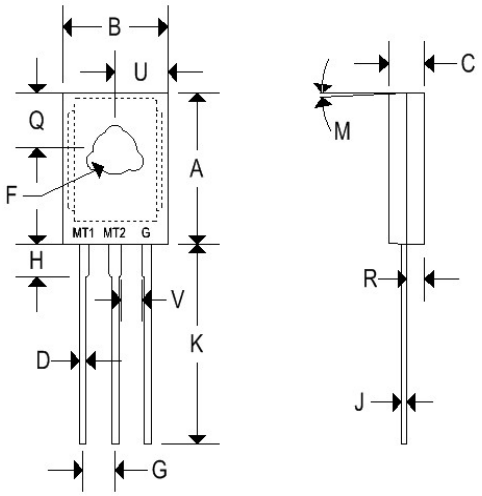
Characteristic	Symbol	Min	Typ.	Max	Unit
Holding current (either direction) (main terminal voltage= 12V, gate open, initiating current = 200mA)	I_H	-	-	100	mA
Rate of rise of commutation voltage (Rated V_{DRM}, $I_{T(RMS)}$ = 6.0A, commutating di/dt = 4.3A/ms, gate unenergized, T_C = 80°C)	dv/dt(c)	-	5.0	-	V/µs
Critical rate of rise of off-state voltage (V_D = Rated V_{DRM}, exponential voltage rise, gate open, T_C = 25°C) (V_D = Rated V_{DRM}, exponential voltage rise, gate open, T_C = 125°C)	dv/dt	500 200	- -	- -	V/µs

MECHANICAL CHARACTERISTIC

Case	TO-220AB
Marking	Body painted, alpha-numeric
Pin out	See below



	TO-220AB			
	Inches		Millimeters	
	Min	Max	Min	Max
A	0.575	0.620	14.600	15.750
B	0.380	0.405	9.650	10.290
C	0.160	0.190	4.060	4.820
D	0.025	0.035	0.640	0.890
F	0.142	0.147	3.610	3.730
G	0.095	0.105	2.410	2.670
H	0.110	0.155	2.790	3.930
J	0.014	0.022	0.360	0.560
K	0.500	0.562	12.700	14.270
L	0.045	0.055	1.140	1.390
N	0.190	0.210	4.830	5.330
Q	0.100	0.120	2.540	3.040
R	0.080	0.110	2.040	2.790
S	0.045	0.055	1.140	1.390
T	0.235	0.255	5.970	6.480
U	-	0.050	-	1.270
V	0.045	-	1.140	-
Z	-	0.080	-	2.030

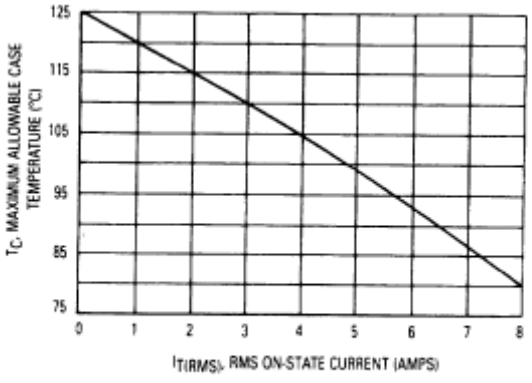


Figure 1. Current Derating

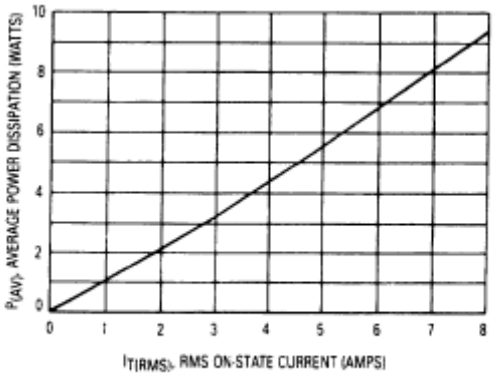


Figure 2. Power Dissipation

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